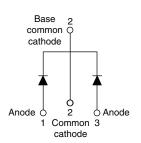


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Schottky Rectifier, 2 x 10 A

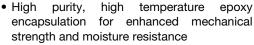


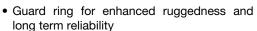


PRODUCT SUMMARY				
Package	TO-220AB			
I _{F(AV)}	2 x 10 A			
V_{R}	80 V, 90 V, 100 V			
V _F at I _F	0.70 V			
I _{RM} max.	6 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Common cathode			
E _{AS}	24 mJ			

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation







RoHS

- Designed and qualified according to JEDEC®-JESD47
- Material categorization: For definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL CHARACTERISTICS VALUES UN						
I _{F(AV)}	Rectangular waveform (per device)	20	Α			
I _{FRM}	T _C = 133 °C per leg	20	Α			
V _{RRM}		80/100	V			
I _{FSM}	t _p = 5 μs sine	850	Α			
V _F	10 A _{pk} , T _J = 125 °C	0.70	V			
T _J	Range	- 65 to + 150	°C			

VOLTAGE RATINGS									
PARAMETER	SYMBOL	MBR2080CT PbF	MBR2080CT -N3	MBR2090CT PbF	MBR2090CT -N3	MBR20100CT PbF	MBR20100CT -N3	UNITS	
Maximum DC reverse voltage	V _R	80		90		100		V	
Maximum working peak reverse voltage	V _{RWM}			š		1	50	V	



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ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average per leg			T 400.00 + 11/4		10		
forward current	per device	I _{F(AV)}	$T_C = 133 ^{\circ}\text{C}$, rated V_R	20			
Peak repetitive forward current per leg		I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 133 °C		20		
Non-repetitive peak surge current		I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	850	Α	
			Surge applied at rated load single phase, 60 Hz	Surge applied at rated load conditions halfwave, ingle phase, 60 Hz			
Peak repetitive reverse s	surge current	I _{RRM}	2.0 μs, 1.0 kHz		0.5		
Non-repetitive avalanche	e energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 12 mH		24	mJ	

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CON	DITIONS	VALUES	UNITS	
Maximum forward voltage drop		10 A	T _{.1} = 25 °C	0.80	V	
	V _{FM} ⁽¹⁾	20 A	1j=25 C	0.95		
	VFM (1)	10 A	T _{.1} = 125 °C	0.70		
		20 A	1 1j = 125 C	0.85		
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Data d DO valta as	0.10	mA	
Maximum instantaneous reverse current		T _J = 125 °C	Rated DC voltage	6		
Threshold voltage	V _{F(TO)}	T T manyimum		0.433	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		15.8	mΩ	
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		400	pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

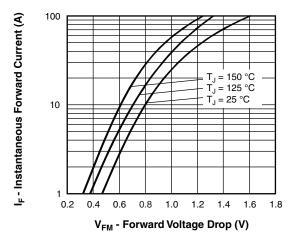
Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction tempe	rature range	T_J		- 65 to 150	°C		
Maximum storage temper	rature range	T _{Stg}		- 65 to 175	C		
Maximum thermal resistar junction to case per leg	nce,	R _{thJC}	DC operation	2.0			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50	°C/W		
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation (For D ² PAK and TO-262)	50			
Approximate weight				2	g		
Approximate weight				0.07	OZ.		
Mounting toward	minimum			6 (5)	kg∙ cm		
Mounting torque	maximum			12 (10)	(lbf·in)		
Marking device				MBR2 MBR2 MBR20	090CT		

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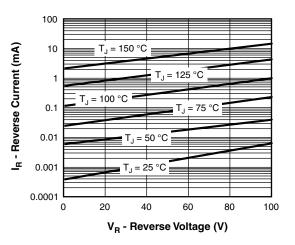


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

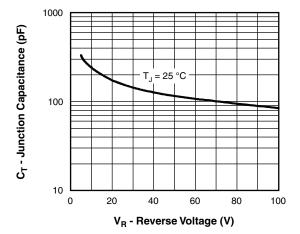


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

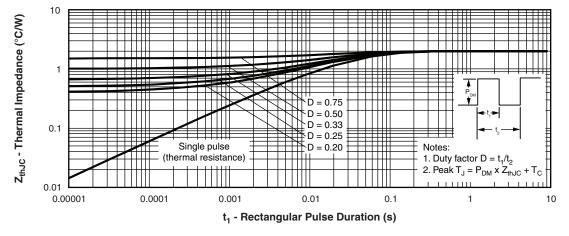


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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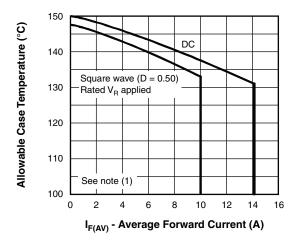


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

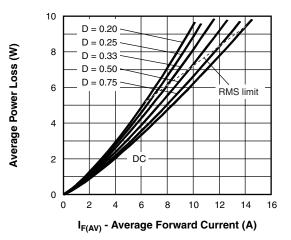


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

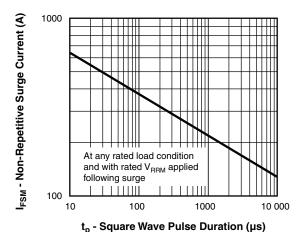


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

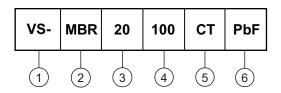
Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Schottky MBR series

Current rating (20 = 20 A)

080 = 80 V

Voltage ratings

090 = 90 V

CT = Essential part number

100 = 100 V

• PbF = Lead (Pb)-free

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-MBR2080CTPbF	50	1000	Antistatic plastic tube					
VS-MBR2080CT-N3	50	1000	Antistatic plastic tube					
VS-MBR2090CTPbF	50	1000	Antistatic plastic tube					
VS-MBR2090CT-N3	50	1000	Antistatic plastic tube					
VS-MBR20100CTPbF	50	1000	Antistatic plastic tube					
VS-MBR20100CT-N3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Dort marking information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



Legal Disclaimer Notice

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